

# Engineering Electromagnetics

Chapter 6:

## **Capacitance**

# Capacitance Defined

A simple capacitor consists of two oppositely charged conductors surrounded by a uniform dielectric.

An increase in  $Q$  by some factor results in an increase in  $\mathbf{E}$  (and in  $\mathbf{D}$ ) by the same factor.

$$\text{where } Q = \oint_S \mathbf{D} \cdot d\mathbf{S}$$

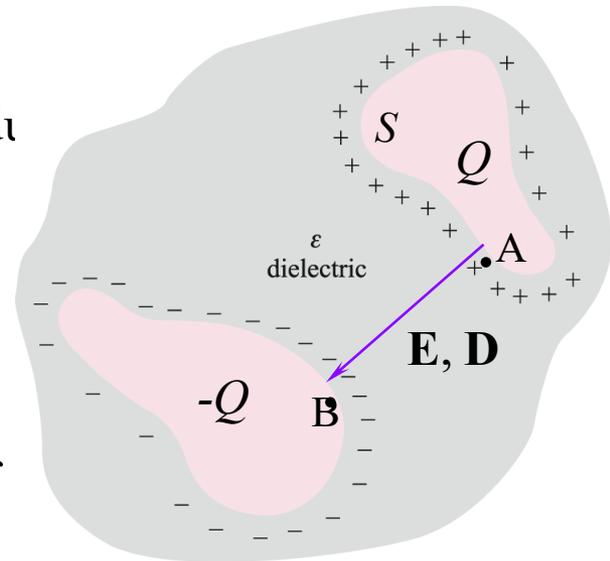
Consequently, the potential difference between conductors

$$V_0 = - \int_B^A \mathbf{E} \cdot d\mathbf{L}$$

will also increase by the same factor -- so the ratio of  $Q$  to  $V_0$  is a constant. We define the *capacitance* of the structure as the ratio of the stored charge to the applied voltage, or

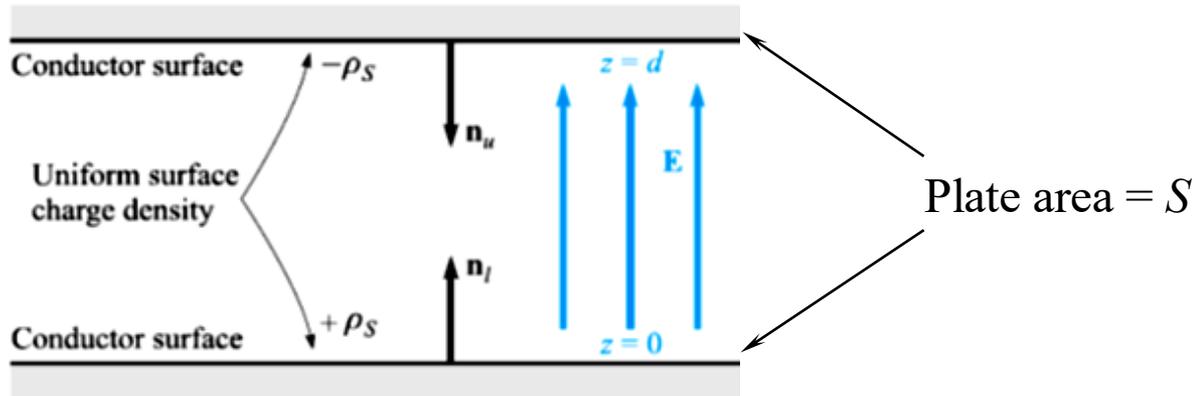
$$C = \frac{Q}{V_0}$$

Units are Coul/V or *Farads*



# Parallel Plate Capacitor

The horizontal dimensions are assumed to be much greater than the plate separation,  $d$ . Therefore, electric field can be assumed to lie only in the  $z$  direction, and potential varies only with  $z$ .



Apply the boundary for  $\mathbf{D}$  at the surface of a perfect conductor:

$$\text{Lower plate: } \mathbf{D} \cdot \mathbf{n}_l \Big|_{z=0} = \mathbf{D} \cdot \mathbf{a}_z = \rho_s \Rightarrow \underline{\mathbf{D} = \rho_s \mathbf{a}_z}$$

$$\text{Upper Plate: } \mathbf{D} \cdot \mathbf{n}_u \Big|_{z=d} = \mathbf{D} \cdot (-\mathbf{a}_z) = -\rho_s \Rightarrow \underline{\mathbf{D} = \rho_s \mathbf{a}_z}$$

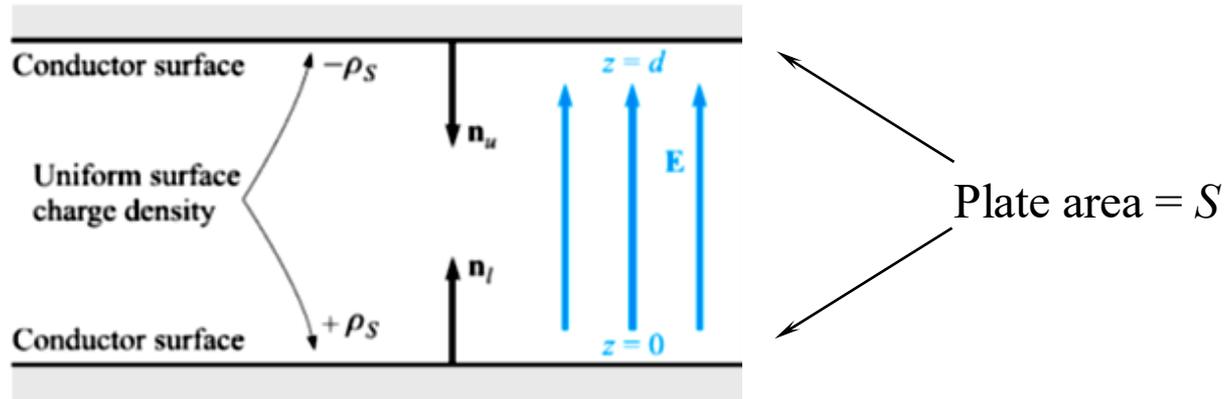
} Same result either way!

Application of the boundary condition is needed on *only one* surface to obtain the total field between plates.

The electric field between plates is therefore:

$$\mathbf{E} = \frac{\rho_s}{\epsilon} \mathbf{a}_z$$

# Capacitance of a Parallel Plate Capacitor



Now with  $\mathbf{E} = \frac{\rho_s}{\epsilon} \mathbf{a}_z$

$$\begin{aligned} Q &= \rho_s S \\ V_0 &= \frac{\rho_s}{\epsilon} d \end{aligned}$$

The voltage between plate can be found through:

$$V_0 = - \int_{\text{upper}}^{\text{lower}} \mathbf{E} \cdot d\mathbf{L} = - \int_d^0 \frac{\rho_s}{\epsilon} dz = \frac{\rho_s}{\epsilon} d$$

Then with  $Q = \rho_s S$  we finally obtain

$$C = \frac{Q}{V_0} = \frac{\epsilon S}{d}$$

# Stored Energy in a Capacitor

Stored energy is found by integrating the energy density in the electric field over the capacitor volume. We use:

$$W_E = \int_{vol} \frac{1}{2} \mathbf{D} \cdot \mathbf{E} dv$$

or

$$W_E = \frac{1}{2} \int_{vol} \epsilon E^2 dv = \frac{1}{2} \int_S \int_0^d \frac{\epsilon \rho_S^2}{\epsilon^2} dz dS = \frac{1}{2} \frac{\rho_S^2}{\epsilon} Sd = \frac{1}{2} \underbrace{\frac{\epsilon S}{d}}_C \underbrace{\frac{\rho_S^2 d^2}{\epsilon^2}}_{V_0^2}$$

There are three ways of writing the energy:

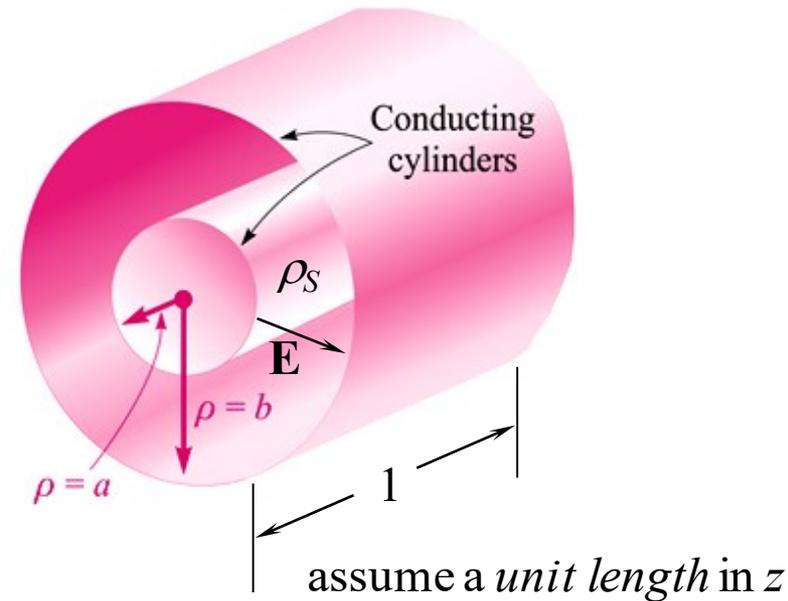
$$W_E = \frac{1}{2} C V_0^2 = \frac{1}{2} Q V_0 = \frac{1}{2} \frac{Q^2}{C}$$

# Example: Coaxial Transmission Line

We previously found using Gauss' Law:

$$\mathbf{E}(\rho) = \frac{a\rho_s}{\epsilon\rho} \mathbf{a}_\rho \text{ V/m} \quad (a < \rho < b)$$

$\mathbf{E} = 0$  elsewhere, assuming a hollow inner conductor, and equal and opposite charges on the inner and outer conductors.



The potential difference between conductors is now:

$$V_0 = - \int_b^a \mathbf{E} \cdot d\mathbf{L} = - \int_b^a \frac{a\rho_s}{\epsilon\rho} \mathbf{a}_\rho \cdot \mathbf{a}_\rho d\rho = \frac{a\rho_s}{\epsilon} \ln \left( \frac{b}{a} \right)$$

...and the charge on the inner conductor per unit length is:

$$Q = \underline{2\pi a(1)\rho_s}$$

Finally:

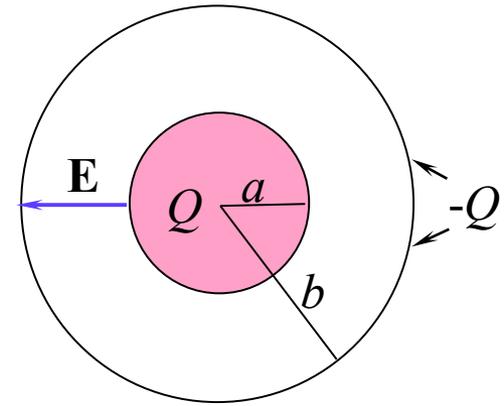
$$C = \frac{Q}{V_0} = \frac{2\pi\epsilon}{\ln(b/a)} \text{ F/m}$$

# Another Example: Spherical Capacitor

Consider two concentric spherical conductors, having radii  $a$  and  $b$ . Equal and opposite charges,  $Q$ , are on the inner and outer conductors.

Gauss' Law tells us that electric field will exist only in the region between spheres, and will be given by:

$$\mathbf{E} = E_r \mathbf{a}_r = \frac{Q}{4\pi\epsilon r^2} \mathbf{a}_r$$



The potential difference between inner and outer spheres is then:

$$V_0 = - \int_b^a \mathbf{E} \cdot d\mathbf{L} = - \int_b^a \frac{Q}{4\pi\epsilon r^2} \mathbf{a}_r \cdot \mathbf{a}_r dr = \frac{Q}{4\pi\epsilon} \left( \frac{1}{a} - \frac{1}{b} \right)$$

and the capacitance is:

$$C = \frac{Q}{V_0} = \frac{4\pi\epsilon}{(1/a) - (1/b)}$$

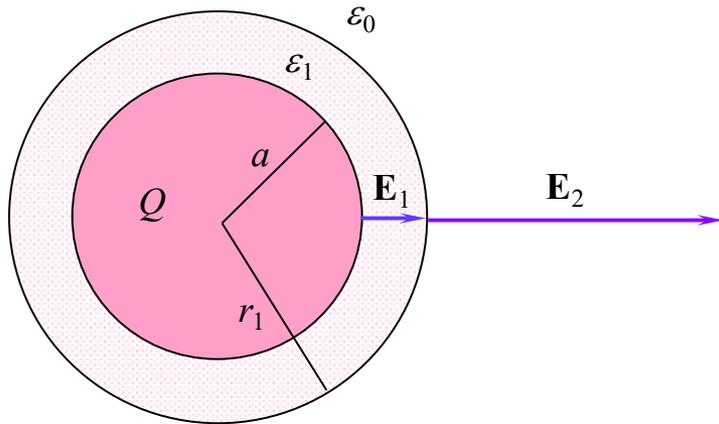
Note that as  $b \rightarrow \infty$  (isolated sphere)

$$C \rightarrow 4\pi\epsilon a$$

# Example: Isolated Sphere with a Dielectric Coating

A conducting sphere of radius  $a$  carries charge  $Q$ .

A dielectric layer of thickness  $r_1 - a$  and of permittivity  $\epsilon_1$  surrounds the conductor. Electric field in the two regions is found from Gauss' Law to be:



$$E_r = \frac{Q}{4\pi\epsilon_1 r^2} \quad (a < r < r_1)$$
$$= \frac{Q}{4\pi\epsilon_0 r^2} \quad (r_1 < r)$$

The potential at the sphere surface is (with zero reference at infinity):

$$V_a - V_\infty = - \int_{r_1}^a \frac{Q dr}{4\pi\epsilon_1 r^2} - \int_\infty^{r_1} \frac{Q dr}{4\pi\epsilon_0 r^2} = \frac{Q}{4\pi} \left[ \frac{1}{\epsilon_1} \left( \frac{1}{a} - \frac{1}{r_1} \right) + \frac{1}{\epsilon_0 r_1} \right] = V_0$$

and the capacitance is:

$$C = \frac{4\pi}{\frac{1}{\epsilon_1} \left( \frac{1}{a} - \frac{1}{r_1} \right) + \frac{1}{\epsilon_0 r_1}}$$

# Capacitor with a Two-Layer Dielectric

In this case, we use the fact that **D normal** to an interface between two dielectrics will be continuous across the boundary, assuming no surface charge is present there:

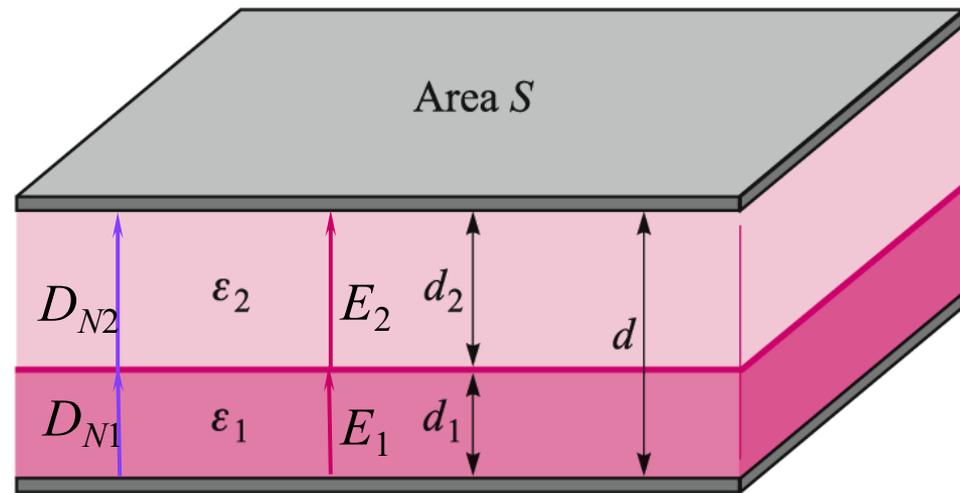
Thus  $D_{N1} = D_{N2}$  and therefore:  $\epsilon_1 E_1 = \epsilon_2 E_2$

The potential difference between bottom and top plates will be:  $V_0 = E_1 d_1 + E_2 d_2$

..which leads to:  $E_1 = \frac{V_0}{d_1 + d_2(\epsilon_1/\epsilon_2)}$

The surface charge density on the bottom plate:

$$\rho_{S1} = D_1 = \epsilon_1 E_1 = \frac{V_0}{\frac{d_1}{\epsilon_1} + \frac{d_2}{\epsilon_2}}$$



The capacitance is then:  $C = \frac{Q}{V_0} = \frac{\rho_S S}{V_0} = \frac{1}{\frac{d_1}{\epsilon_1 S} + \frac{d_2}{\epsilon_2 S}} = \frac{1}{\frac{1}{C_1} + \frac{1}{C_2}}$

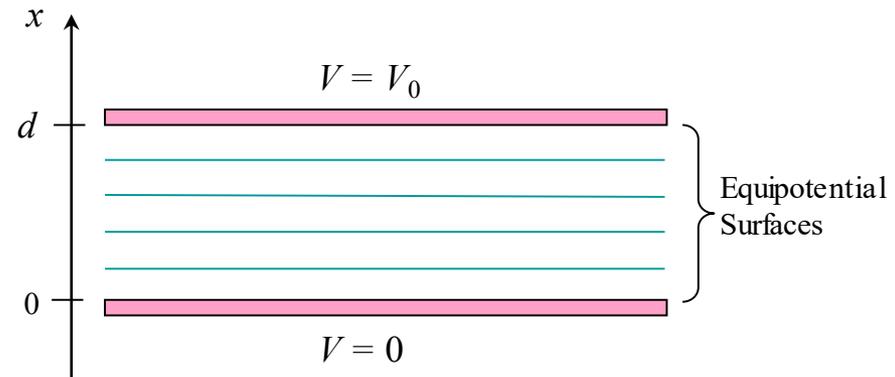
# Poisson's and Laplace's Equations

These equations allow one to find the **potential field** in a region, in which values of potential or electric field are **known at its boundaries**.

Start with Maxwell's first equation:  $\nabla \cdot \mathbf{D} = \rho_v$

where  $\mathbf{D} = \epsilon \mathbf{E}$

and  $\mathbf{E} = -\nabla V$



so that  $\nabla \cdot \mathbf{D} = \nabla \cdot (\epsilon \mathbf{E}) = -\nabla \cdot (\epsilon \nabla V) = \rho_v$

or finally: 
$$\nabla \cdot \nabla V = -\frac{\rho_v}{\epsilon}$$

# Derivation (continued)

Recall the divergence as expressed in rectangular coordinates:

$$\nabla \cdot \mathbf{A} = \frac{\partial A_x}{\partial x} + \frac{\partial A_y}{\partial y} + \frac{\partial A_z}{\partial z}$$

...and the gradient:

$$\nabla V = \frac{\partial V}{\partial x} \mathbf{a}_x + \frac{\partial V}{\partial y} \mathbf{a}_y + \frac{\partial V}{\partial z} \mathbf{a}_z$$

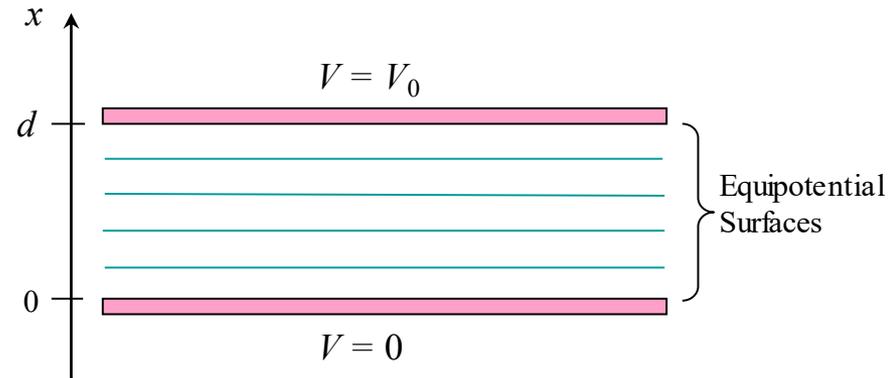
then:

$$\begin{aligned} \nabla \cdot \nabla V &= \frac{\partial}{\partial x} \left( \frac{\partial V}{\partial x} \right) + \frac{\partial}{\partial y} \left( \frac{\partial V}{\partial y} \right) + \frac{\partial}{\partial z} \left( \frac{\partial V}{\partial z} \right) \\ &= \frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} + \frac{\partial^2 V}{\partial z^2} \end{aligned}$$

$\nabla \cdot \nabla$  is abbreviated  $\nabla^2$  (and pronounced “del squared”). It is known as the **Laplacian** operator

# Statement of Poisson's and Laplace's Equations

we already have:  $\nabla \cdot \nabla V = -\frac{\rho_v}{\epsilon}$



which becomes:

$$\nabla^2 V = \frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} + \frac{\partial^2 V}{\partial z^2} = -\frac{\rho_v}{\epsilon}$$

This is **Poisson's equation**, as stated in rectangular coordinates.

In the event that there is **zero** volume charge density, the right-hand-side becomes zero, and we obtain

**Laplace's equation:**

$$\nabla^2 V = 0$$

# The Laplacian Operator in the Three Coordinate Systems

$$\nabla^2 V = \frac{\partial^2 V}{\partial x^2} + \frac{\partial^2 V}{\partial y^2} + \frac{\partial^2 V}{\partial z^2} = 0 \quad (\text{rectangular}) \quad (\text{Laplace's equation})$$

$$\nabla^2 V = \frac{1}{\rho} \frac{\partial}{\partial \rho} \left( \rho \frac{\partial V}{\partial \rho} \right) + \frac{1}{\rho^2} \left( \frac{\partial^2 V}{\partial \phi^2} \right) + \frac{\partial^2 V}{\partial z^2} \quad (\text{cylindrical})$$

$$\nabla^2 V = \frac{1}{r^2} \frac{\partial}{\partial r} \left( r^2 \frac{\partial V}{\partial r} \right) + \frac{1}{r^2 \sin \theta} \frac{\partial}{\partial \theta} \left( \sin \theta \frac{\partial V}{\partial \theta} \right) + \frac{1}{r^2 \sin^2 \theta} \frac{\partial^2 V}{\partial \phi^2} \quad (\text{spherical})$$

# Application on Laplace and Poisson equations: Parallel Plate Capacitor

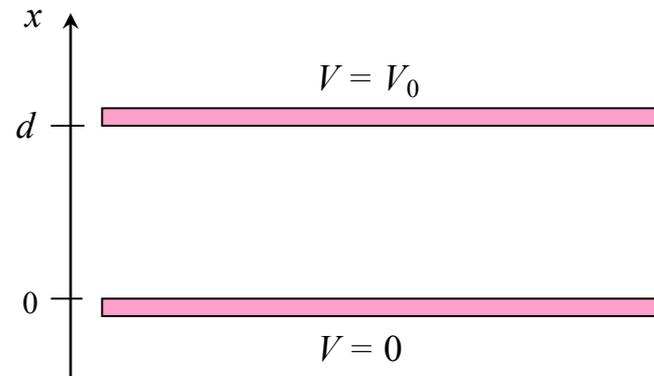
In this case, the plate separation,  $d$ , is assumed much less than the smallest plate dimension. Therefore  $V$  can be assumed to vary only with  $x$ .

Laplace's equation reduces to:

$$\frac{d^2 V}{dx^2} = 0$$

Integrating once, obtain:  $\frac{dV}{dx} = A$

Integrate a second time to get:  $V = Ax + B$



Boundary conditions:

1.  $V = 0$  at  $x = 0$
2.  $V = V_0$  at  $x = d$

where  $A$  and  $B$  are integration constants that are to be evaluated subject to the boundary conditions.

# Interior Potential Field

We now have:  $V = Ax + B$

Apply boundary condition 1:

$$0 = A(0) + B \quad \longrightarrow \quad \underline{B = 0}$$

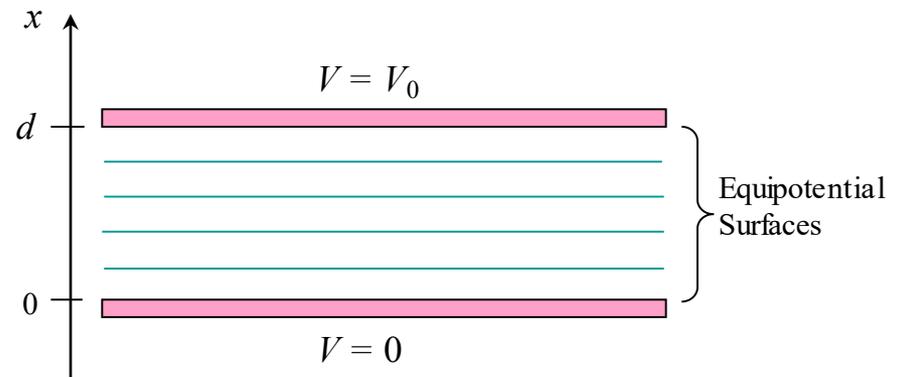
Apply boundary condition 2:

$$V_0 = Ad \quad \longrightarrow \quad \underline{A = \frac{V_0}{d}}$$

Finally:

$$V = \frac{V_0 x}{d}$$

This function is pictured by the equipotential surfaces shown in the capacitor, in which there is a constant voltage difference between adjacent surfaces



Boundary conditions:

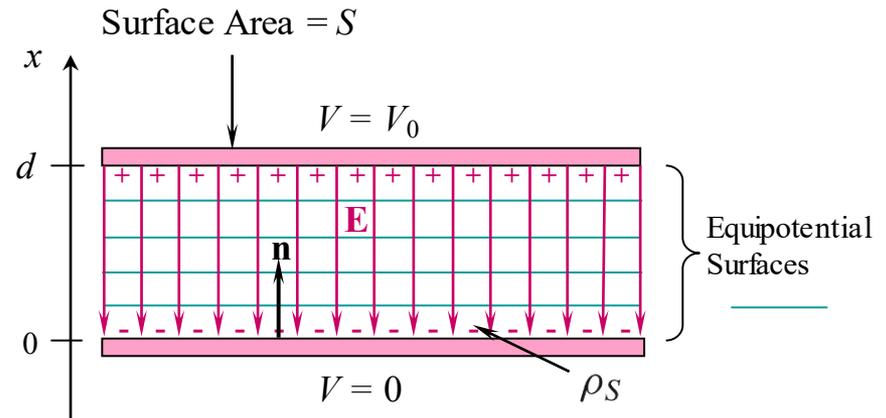
1.  $V = 0$  at  $x = 0$
2.  $V = V_0$  at  $x = d$

# Finding the Electric Field, Charge, and Capacitance

Start with:  $V = V_0 \frac{x}{d}$

Then:  $\mathbf{E} = -\nabla V = -\frac{V_0}{d} \mathbf{a}_x$

From which:  $\mathbf{D} = -\epsilon \frac{V_0}{d} \mathbf{a}_x$



At the lower plate surface:  $\mathbf{D}_S = \mathbf{D}|_{x=0} = -\epsilon \frac{V_0}{d} \mathbf{a}_x$  and  $\mathbf{n} = \mathbf{a}_x$

Then use:  $\mathbf{D} \cdot \mathbf{n}|_S = \rho_S$  to find  $D_N = -\epsilon \frac{V_0}{d} = \rho_S$

The charge on the lower plate is now:

$$Q = \int_S \frac{-\epsilon V_0}{d} dS = -\epsilon \frac{V_0 S}{d}$$

and the capacitance is

$$C = \frac{|Q|}{V_0} = \frac{\epsilon S}{d}$$

# Another Example: Coaxial Transmission Line

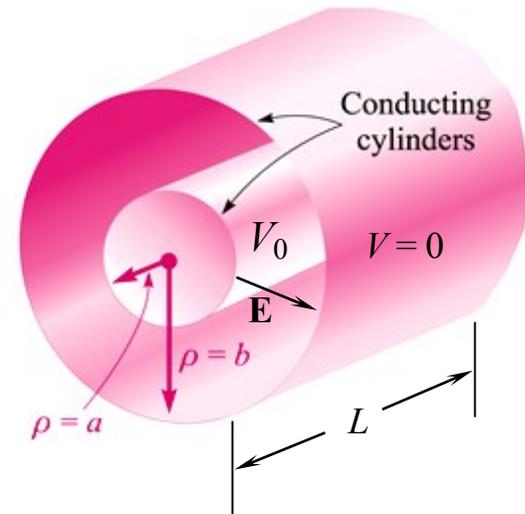
As  $V$  is assumed to vary with radius only, Laplace's equation becomes:

$$\frac{1}{\rho} \frac{\partial}{\partial \rho} \left( \rho \frac{\partial V}{\partial \rho} \right) = 0 \quad (\text{not valid at } \rho = 0)$$

Our goal is to evaluate the potential function in the region ( $a < \rho < b$ )

Integrate once:  $\rho \frac{dV}{d\rho} = A$

.. and a second time:  $V = A \ln \rho + B$



Boundary conditions:

1.  $V = 0$  at  $\rho = b$
2.  $V = V_0$  at  $\rho = a$

# Coaxial Line: continued

Now have:  $V = A \ln \rho + B$

Apply boundary condition 1:

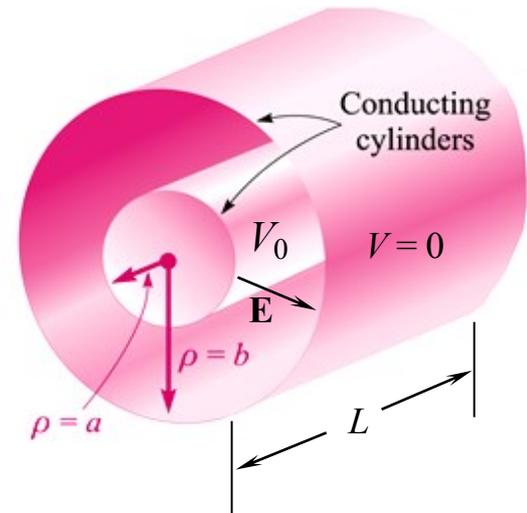
$$0 = A \ln(b) + B \Rightarrow \underline{B = -A \ln(b)}$$

Apply boundary condition 2:

$$V_0 = A \ln(a) - A \ln(b) = A \ln(a/b) \Rightarrow \underline{A = -\frac{V_0}{\ln(b/a)}}$$

Putting it all together:

$$V(\rho) = -\frac{V_0}{\ln(b/a)} [\ln(\rho) - \ln(b)] = \boxed{V_0 \frac{\ln(b/\rho)}{\ln(b/a)}}$$



Boundary conditions:

1.  $V = 0$  at  $\rho = b$
2.  $V = V_0$  at  $\rho = a$

# Coaxial Line Capacitance

We have found the potential field between conductors:

$$V(\rho) = V_0 \frac{\ln(b/\rho)}{\ln(b/a)}$$

Then:

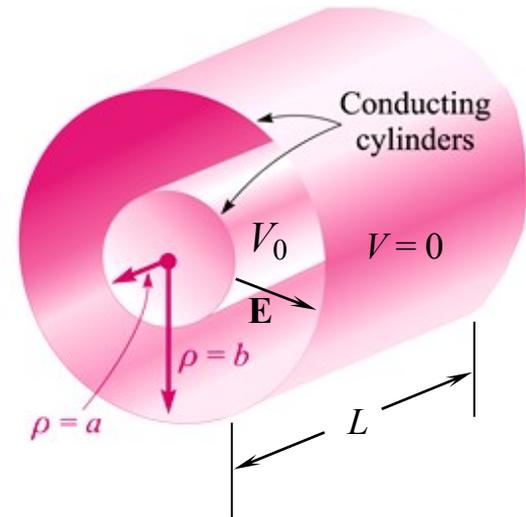
$$\mathbf{E} = -\nabla V = -\frac{dV}{d\rho} \mathbf{a}_\rho = \frac{V_0}{\rho} \frac{1}{\ln(b/a)} \mathbf{a}_\rho$$

The charge density on the inner conductor is:

$$\rho_s = \mathbf{D} \cdot \mathbf{a}_\rho \Big|_{\rho=a} = \frac{\epsilon V_0}{a} \frac{1}{\ln(b/a)} \text{ C/m}^2$$

The total charge on the inner conductor is:

$$Q = \int_S \rho_s da = 2\pi a L \rho_s = \frac{2\pi\epsilon L V_0}{\ln(b/a)} \text{ C}$$



...and the capacitance is finally:

$$C = \frac{Q}{V_0} = \frac{2\pi\epsilon L}{\ln(b/a)} \text{ F}$$

6.2. Let  $S = 100 \text{ mm}^2$ ,  $d = 3 \text{ mm}$ , and  $\epsilon_r = 12$  for a parallel-plate capacitor.

a) Calculate the capacitance:

$$C = \frac{\epsilon_r \epsilon_0 A}{d} = \frac{12 \epsilon_0 (100 \times 10^{-6})}{3 \times 10^{-3}} = 0.4 \epsilon_0 = \underline{3.54 \text{ pf}}$$

b) After connecting a 6 V battery across the capacitor, calculate  $E$ ,  $D$ ,  $Q$ , and the total stored electrostatic energy: First,

$$E = V_0/d = 6/(3 \times 10^{-3}) = \underline{2000 \text{ V/m}}, \quad \text{then } D = \epsilon_r \epsilon_0 E = 2.4 \times 10^4 \epsilon_0 = \underline{0.21 \mu\text{C/m}^2}$$

The charge in this case is

$$Q = \mathbf{D} \cdot \mathbf{n}|_s = DA = 0.21 \times (100 \times 10^{-6}) = 0.21 \times 10^{-4} \mu\text{C} = \underline{21 \text{ pC}}$$

Finally,  $W_e = (1/2)QV_0 = 0.5(21)(6) = \underline{63 \text{ pJ}}$ .

c) With the source still connected, the dielectric is carefully withdrawn from between the plates. With the dielectric gone, re-calculate  $E$ ,  $D$ ,  $Q$ , and the energy stored in the capacitor.

$$E = V_0/d = 6/(3 \times 10^{-3}) = \underline{2000 \text{ V/m}}, \quad \text{as before. } D = \epsilon_0 E = 2000 \epsilon_0 = \underline{17.7 \text{ nC/m}^2}$$

The charge is now  $Q = DA = 17.7 \times (100 \times 10^{-6}) \text{ nC} = \underline{1.8 \text{ pC}}$ .

Finally,  $W_e = (1/2)QV_0 = 0.5(1.8)(6) = \underline{5.4 \text{ pJ}}$ .